



2N65-LC1

Power MOSFET

2.0A, 650V N-CHANNEL POWER MOSFET

DESCRIPTION

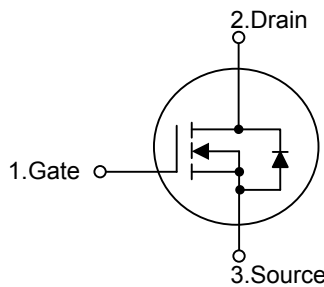
The UTC **2N65-LC1** is an N-channel power MOSFET using UTC's advanced technology to provide customers with a minimum on-state resistance and superior switching performance.

The UTC **2N65-LC1** is generally applied in low power switching mode power appliances and electronic ballast.

FEATURES

- * $R_{DS(ON)} \leq 5.5 \Omega @ V_{GS}=10V, I_D=1.0A$
- * High Switching Speed
- * 100% Avalanche Tested

SYMBOL

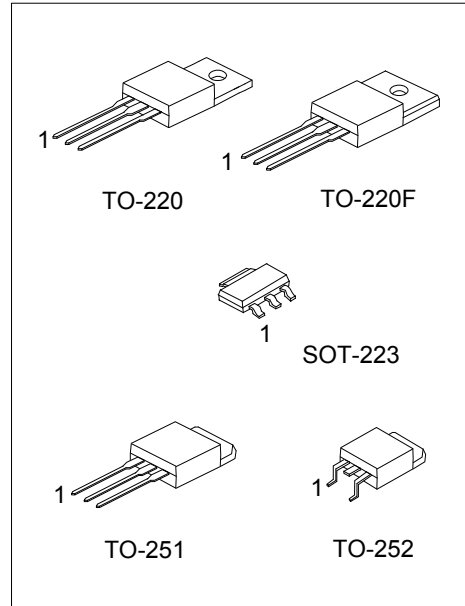


ORDERING INFORMATION

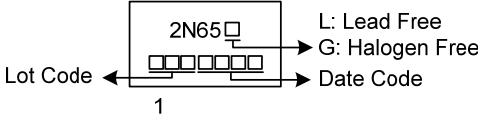
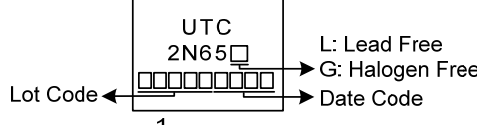
Ordering Number		Package	Pin Assignment			Packing
Lead Free	Halogen Free		1	2	3	
2N65L-AA3-R	2N65G-AA3-R	SOT-223	G	D	S	Tape Reel
2N65L-TA3-T	2N65G-TA3-T	TO-220	G	D	S	Tube
2N65L-TF3-T	2N65G-TF3-T	TO-220F	G	D	S	Tube
2N65L-TM3-T	2N65G-TM3-T	TO-251	G	D	S	Tube
2N65L-TN3-R	2N65G-TN3-R	TO-252	G	D	S	Tape Reel

Note: Pin Assignment: G: Gate D: Drain S: Source

<p>2N65G-AA3-R</p> <p>(1) Packing Type</p> <p>(2) Package Type</p> <p>(3) Green Package</p>	<p>(1) R: Tape Reel, T: Tube</p> <p>(2) AA3: SOT-223, TA3: TO-220, TF3: TO-220F</p> <p>TM3: TO-251, TN3: TO-252</p> <p>(3) G: Halogen Free and Lead Free, L: Lead Free</p>
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MARKING

SOT-223	TO-220 / TO-220F / TO-251 / TO-252
 <p>Diagram showing the marking on a SOT-223 package. The marking includes the part number '2N65', a lead-free symbol (L), a halogen-free symbol (G), a date code, and a lot code. The number '1' is located below the marking area.</p>	 <p>Diagram showing the marking on TO-220 / TO-220F / TO-251 / TO-252 packages. The marking includes the manufacturer 'UTC', the part number '2N65', a lead-free symbol (L), a halogen-free symbol (G), a date code, and a lot code. The number '1' is located below the marking area.</p>

■ ABSOLUTE MAXIMUM RATINGS ($T_c=25^\circ\text{C}$, unless otherwise specified)

PARAMETER		SYMBOL	RATINGS	UNIT
Drain-Source Voltage		V_{DSS}	650	V
Gate-Source Voltage		V_{GSS}	± 30	V
Drain Current	Continuous	I_D	2	A
	Pulsed (Note 2)	I_{DM}	4	A
Avalanche Energy	Single Pulsed (Note 3)	E_{AS}	28.8	mJ
Peak Diode Recovery dv/dt (Note 4)		dv/dt	2.175	V/ns
Power Dissipation	SOT-223	P_D	3.3	W
	TO-220		54	W
	TO-220F		23	W
	TO-251/TO-252		45	W
Junction Temperature		T_J	+150	$^\circ\text{C}$
Storage Temperature		T_{STG}	-55 ~ +150	$^\circ\text{C}$

Notes: 1. Absolute maximum ratings are those values beyond which the device could be permanently damaged.

Absolute maximum ratings are stress ratings only and functional device operation is not implied.

2. Repetitive Rating: Pulse width limited by maximum junction temperature.

3. $L = 10\text{mH}$, $I_{AS} = 2.4\text{A}$, $V_{DD} = 50\text{V}$, $R_G = 25\Omega$, Starting $T_J = 25^\circ\text{C}$

4. $I_{SD} \leq 2.0\text{A}$, $di/dt \leq 200\text{A}/\mu\text{s}$, $V_{DD} \leq BV_{DSS}$, Starting $T_J = 25^\circ\text{C}$

■ THERMAL DATA

PARAMETER		SYMBOL	RATINGS	UNIT
Junction to Ambient	SOT-223	θ_{JA}	150	$^\circ\text{C}/\text{W}$
	TO-220/TO-220F		62.5	$^\circ\text{C}/\text{W}$
	TO-251/TO-252		110	$^\circ\text{C}/\text{W}$
Junction to Case	SOT-223	θ_{JC}	37.8	$^\circ\text{C}/\text{W}$
	TO-220		2.31	$^\circ\text{C}/\text{W}$
	TO-220F		5.4	$^\circ\text{C}/\text{W}$
	TO-251/TO-252		2.77 (Note)	$^\circ\text{C}/\text{W}$

Note: Device mounted on FR-4 substrate P_c board, 2oz copper, with 1inch square copper plate.

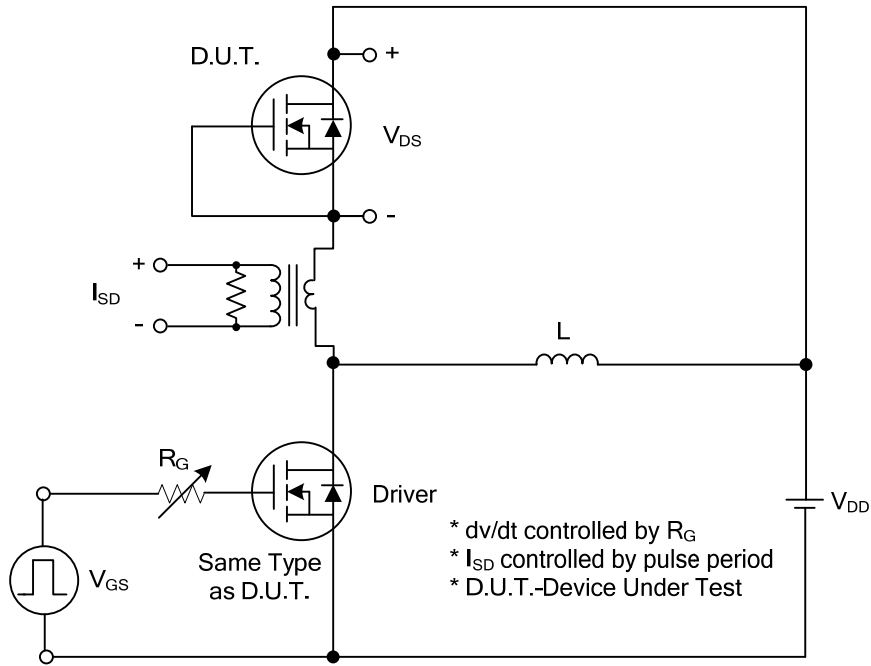
■ ELECTRICAL CHARACTERISTICS ($T_J=25^\circ\text{C}$, unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
OFF CHARACTERISTICS						
Drain-Source Breakdown Voltage	BV_{DSS}	$I_D=250\mu\text{A}$, $V_{GS}=0\text{V}$	650			V
Drain-Source Leakage Current	I_{DSS}	$V_{DS}=650\text{V}$, $V_{GS}=0\text{V}$			10	μA
Gate- Source Leakage Current	Forward	$V_{GS}=+30\text{V}$, $V_{DS}=0\text{V}$			+100	nA
	Reverse		$V_{GS}=-30\text{V}$, $V_{DS}=0\text{V}$			-100
ON CHARACTERISTICS						
Gate Threshold Voltage	$V_{GS(TH)}$	$V_{DS}=V_{GS}$, $I_D=250\mu\text{A}$	2.0		4.0	V
Static Drain-Source On-State Resistance	$R_{DS(ON)}$	$V_{GS}=10\text{V}$, $I_D=1.0\text{A}$		4.7	5.5	Ω
DYNAMIC PARAMETERS						
Input Capacitance	C_{ISS}	$V_{GS}=0\text{V}$, $V_{DS}=25\text{V}$, $f=1.0\text{MHz}$		263		pF
Output Capacitance	C_{OSS}			30		pF
Reverse Transfer Capacitance	C_{RSS}			2.9		pF
SWITCHING PARAMETERS						
Total Gate Charge (Note 1)	Q_G	$V_{DS}=520\text{V}$, $V_{GS}=10\text{V}$, $I_D=2\text{A}$ $I_G=1\text{mA}$ (Note 1, 2)		7.5		nC
Gate to Source Charge	Q_{GS}			2.9		nC
Gate to Drain Charge	Q_{GD}			1		nC
Turn-ON Delay Time (Note 1)	$t_{D(ON)}$	$V_{DD}=100\text{V}$, $V_{GS}=10\text{V}$, $I_D=2\text{A}$, $R_G=25\Omega$ (Note 1, 2)		3.8		ns
Rise Time	t_R			15.5		ns
Turn-OFF Delay Time	$t_{D(OFF)}$			23		ns
Fall-Time	t_F			24.5		ns
SOURCE- DRAIN DIODE RATINGS AND CHARACTERISTICS						
Maximum Body-Diode Continuous Current	I_S				2	A
Maximum Body-Diode Pulsed Current (Note 1)	I_{SM}				4	A
Drain-Source Diode Forward Voltage (Note 1)	V_{SD}	$I_S=2\text{A}$, $V_{GS}=0\text{V}$			1.4	V
Body Diode Reverse Recovery Time	t_{rr}	$I_S=2\text{A}$, $V_{GS}=0\text{V}$, $dI_F/dt=100\text{A}/\mu\text{s}$		280		ns
Body Diode Reverse Recovery Charge	Q_{rr}				0.9	

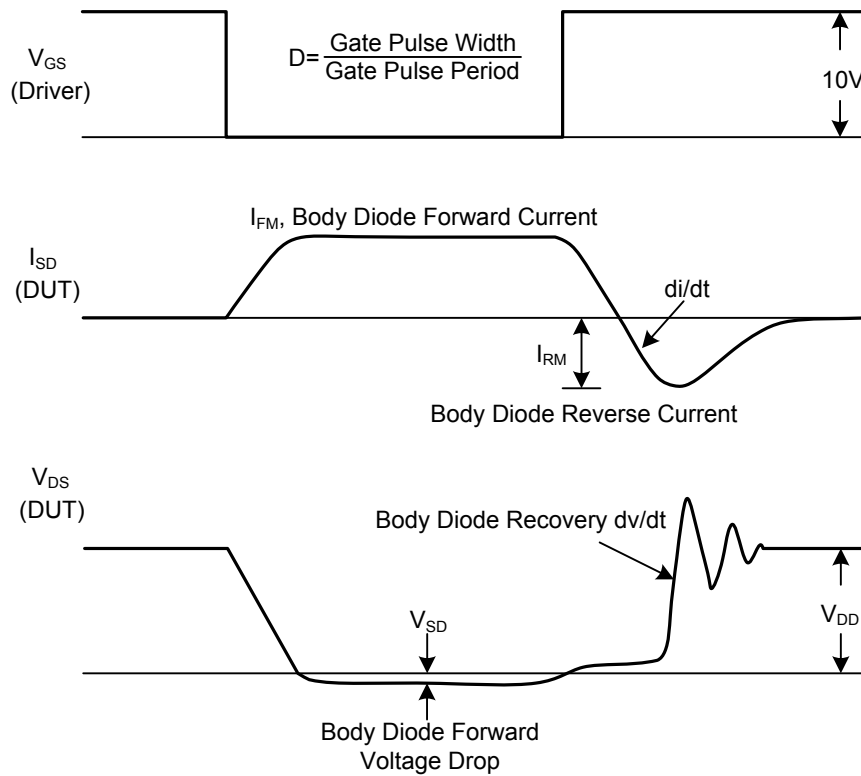
Notes: 1. Pulse Test: Pulse width $\leq 300\mu\text{s}$, Duty cycle $\leq 2\%$.

2. Essentially independent of operating temperature.

TEST CIRCUITS AND WAVEFORMS

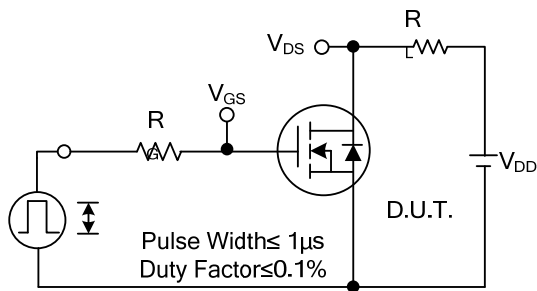


Peak Diode Recovery dv/dt Test Circuit

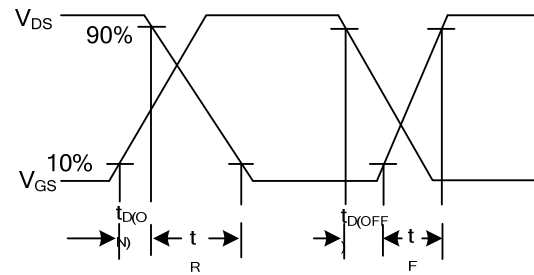


Peak Diode Recovery dv/dt Waveforms

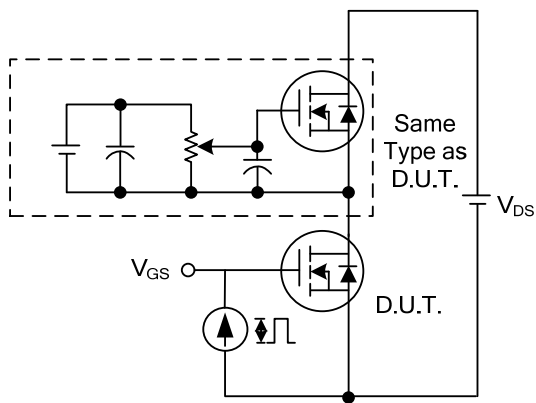
TEST CIRCUITS AND WAVEFORMS



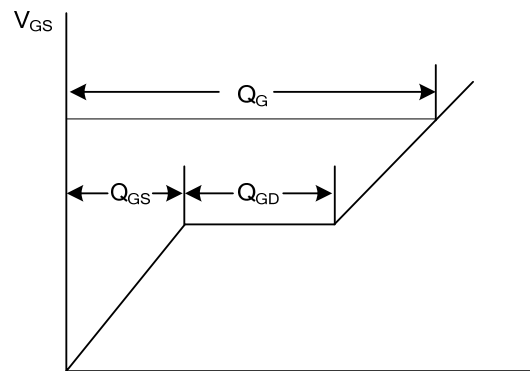
Switching Test Circuit



Switching Waveforms

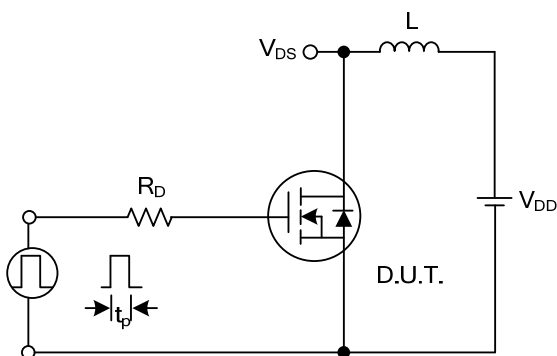


Gate Charge Test Circuit

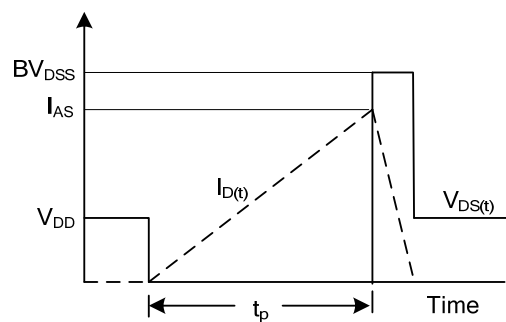


Charge

Gate Charge Waveform

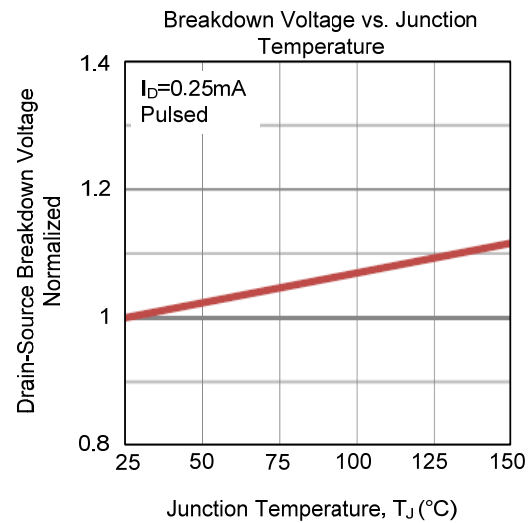
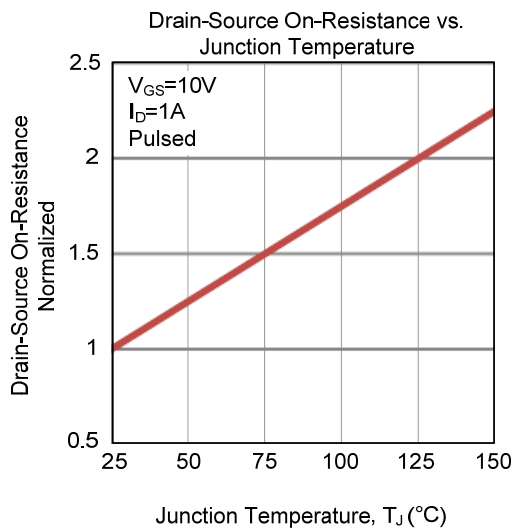
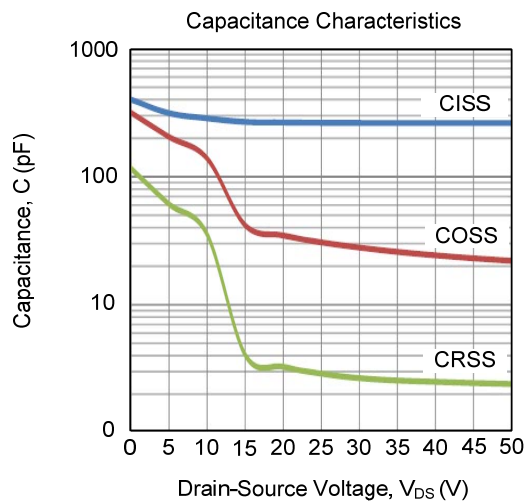
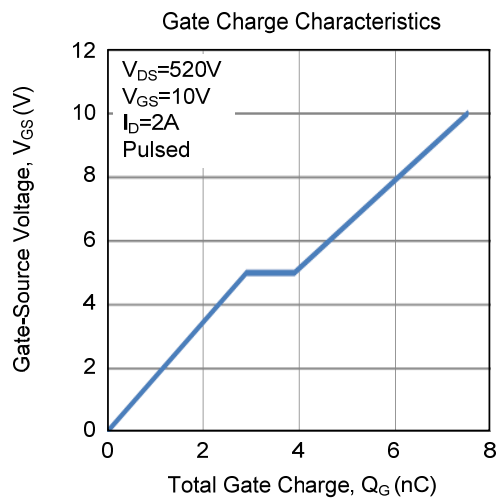
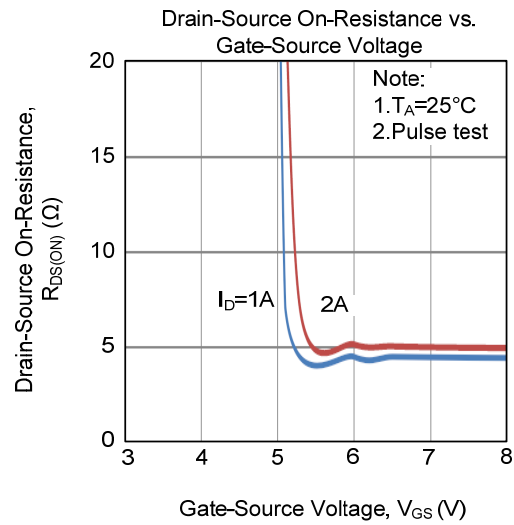
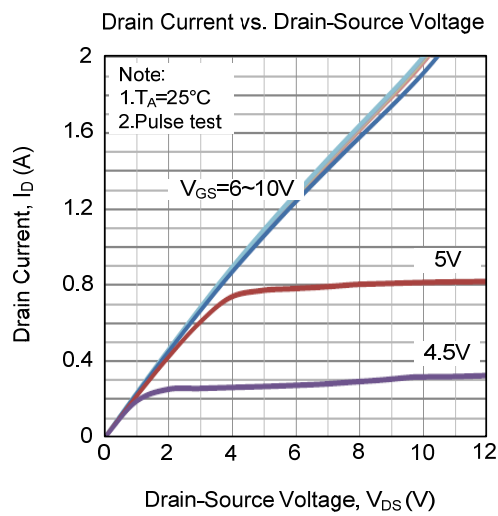


Unclamped Inductive Switching Test Circuit

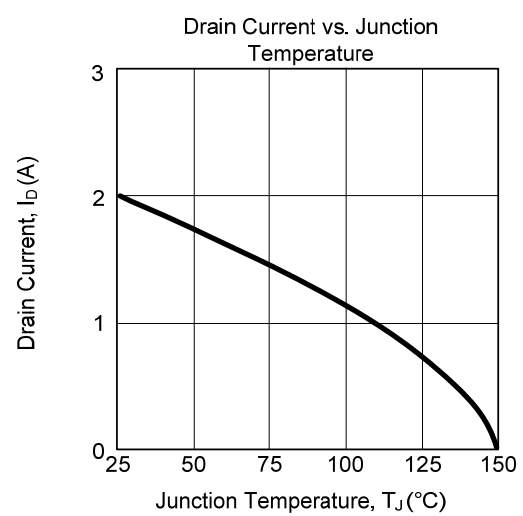
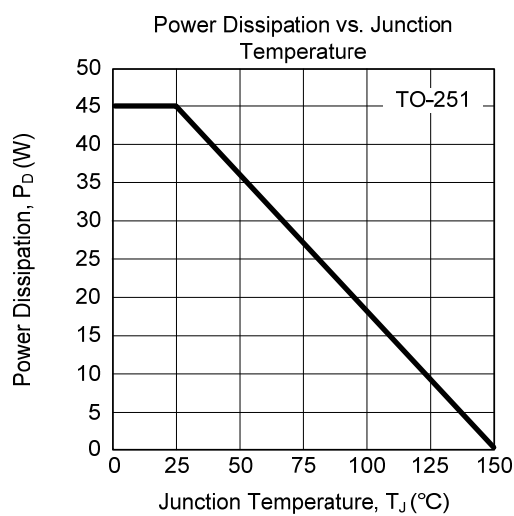
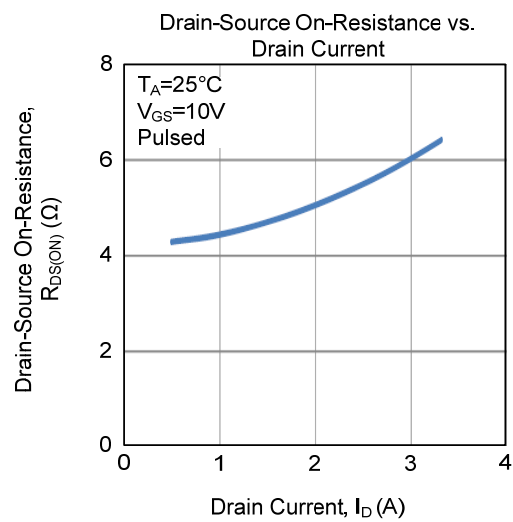
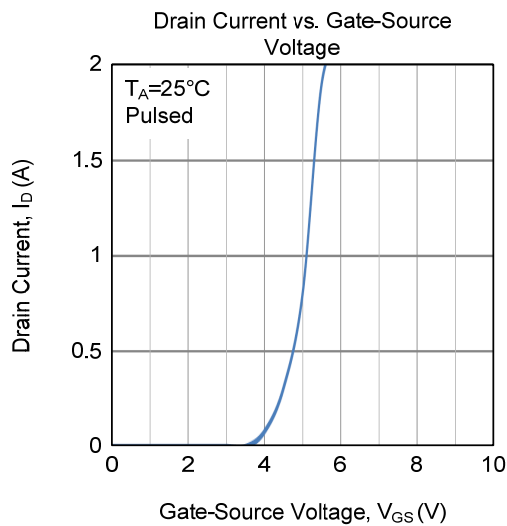
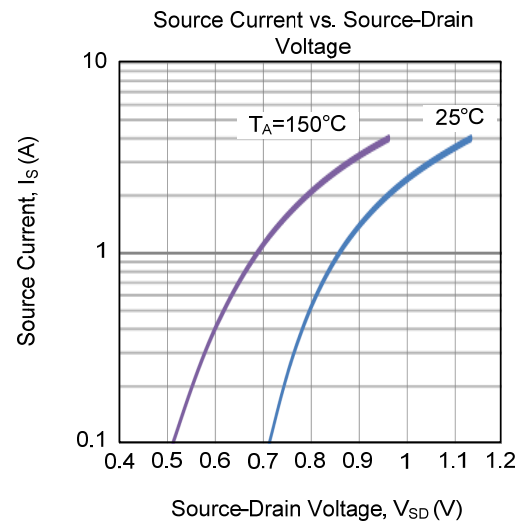
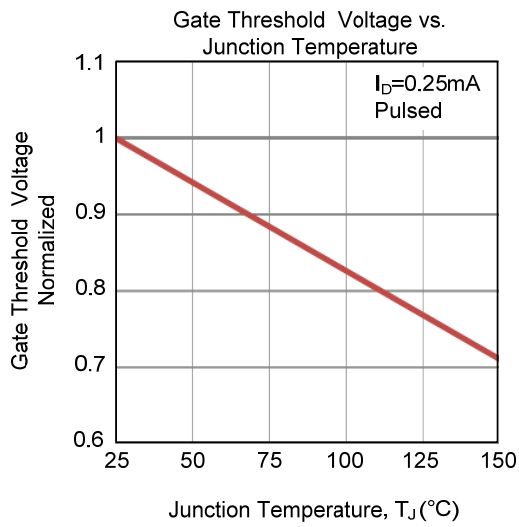


Unclamped Inductive Switching Waveforms

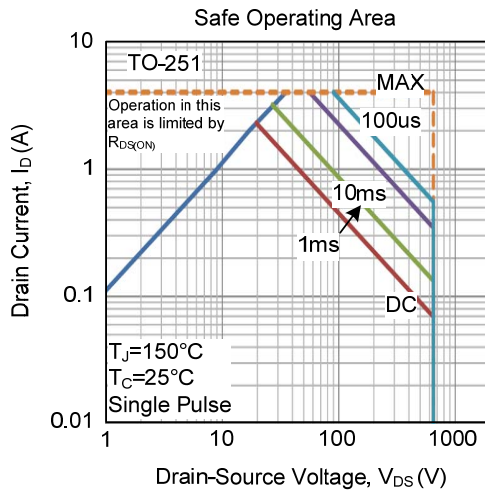
TYPICAL CHARACTERISTICS



■ TYPICAL CHARACTERISTICS (Cont.)



■ TYPICAL CHARACTERISTICS (Cont.)



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